

Low-Voltage, Low R_{ON}, Single Analog Switch In miniQFN-6 Package

DESCRIPTION

The DG2511, DG2512, DG2513 are low on-resistance, single-pole/double-throw or single-pole/single-throw monolithic CMOS analog switch. It is designed for low voltage applications. The DG2511, DG2512, DG2513 are ideal for portable and battery powered equipment, requiring high performance and efficient use of board space. In additional to the low on-resistance (1.3 Ω at 2.7 V).

The DG2511 is an SPDT and the DG2512, DG2513 are SPST. The switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

The DG2511, DG2512, DG2513 are built on Vishay Siliconix's low voltage JI5L process. An epitaxial layer prevents latchup.

Break-before-make is guaranteed.

The DG2511, DG2512, DG2513 represents a breakthrough in packaging development for analog switching products. The miniQFN-6 package (1.2 x 1 mm).

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. For analog switching products manufactured with NiPdAu device terminations, the lead (Pb)-free "-E4" suffix is being used as a designator.

FEATURES

- Low voltage operation (1.8 V to 5.5 V)
- Low on-resistance R_{ON} : 1.3 Ω at 2.7 V
- Low charge injection
- Latch-up current > 300 mA (JESD78A)
- miniQFN-6 package (1.2 x 1 mm)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- Reduced power consumption
- Simple logic interface
- High accuracy
- Reduce board space
- Guaranteed 2 V operation

APPLICATIONS

- Cellular phones •
- Communication systems
- Portable test equipment
- Battery operated systems
- Sample and hold circuits
- ADC and DAC applications
- Low voltage data acquisition systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



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COMPLIANT



ABSOLI	ΙΤΕ ΜΔΧΙΜ	IUM RATINGS
ADOUL		

Parameter		Limit	Unit		
Reference V+ to GND		- 0.3 to + 6	V		
IN, COM, NC, NO ^a		- 0.3 to (V+ + 0.3)			
Continuous Current (NO, NC, COM pins)		± 150	~ ^		
Peak Current (Pulsed at 1 ms, 10 % duty cycle)		± 300	mA		
Storage Temperature	D Suffix	- 65 to 150	°C		
Power Dissipation (Packages) ^b	miniQFN-6 ^c	160	mW		

Notes:

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings. b. All leads welded or soldered to PC board.

c. Derate 2 mW/°C above 70 °C.

		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C			
Parameter	Symbol	$V_{+} = 3 V_{+} \pm 10 \%, V_{ N } = 0.4 V \text{ or } 2 V^{e}$	Temp. ^a	Min. ^b	Typ. ^c Max. ^b		Unit
Analog Switch	Cymbol		Temp.		Typ.	max.	0111
	V _{NO} , V _{NC} ,						
Analog Signal Range ^d	V _{COM}		Full	0		V+	V
On-Resistance	R _{ON}		Room		1.4	1.7	
	-	V+ = 2.7 V, V _{COM} = 0.5 V/1.5 V	Full			1.9	
R _{ON} Match	ΔR _{ON}	I_{NO} , $I_{NC} = 100 \text{ mA}$	Room			0.15	Ω
R _{ON} Flatness	R _{ON} Flatness		Room		0.3	0.4	
	I _{NO(off)}		Room	- 2		2	
Outlete Off Landerson Output	I _{NC(off)}	V+ = 3.3 V,	Full	- 20		20	nA
Switch Off Leakage Current [†]		V_{NO} , V_{NC} = 1 V/3 V, V_{COM} = 3 V/1 V	Room	- 2		2	
	I _{COM(off)}		Full	- 20		20	
Channel-On Leakage Current ^f	I _{COM(on)}	$V_{+} = 3.3 V, V_{NO}, V_{NC} = V_{COM} = 1 V/3 V$	Room	- 2		2	
-			Full	- 20		20	
Digital Control			Full	10	[[1
Input High Voltage	V _{INH}			1.6		0.4	v
Input Low Voltage	V _{INL}		Full			0.4	
Input Capacitance	C _{in}		Full		4		pF
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 or V+	Full	1		1	μA
Dynamic Characteristics	- T			r	10	40	1
Turn-On Time	t _{ON}		Room Full		18	43 49	
		V+ = 2.7 V, V _{NO} or V _{NC} = 1.5 V,	Room		7	32	ns
Turn-Off Time	t _{OFF}	$R_{L} = 50 \ \Omega, \ C_{L} = 35 \ pF$	Full			34	
Break-Before-Make Time	t _{BBM}		Room	1	12		
Charge Injection ^d	Q _{INJ}	C_{L} = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω	Room		3		рC
Off-Isolation ^d	OIRR		Room		- 58		
Crosstalk ^d	X _{TALK}	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$	Room		- 64		dE
	C _{NO(off)}		-				pF
N _O , N _C Off Capacitance ^d	C _{NC(off)}	$V_{IN} = 0$ or V+, f = 1 MHz	Room		21		
Channel-On Capacitance ^d	C _{ON}		Room		61		
Power Supply	<u> </u>						
Power Supply Range	V+			1.8		5.5	V
Power Supply Current	I+	V _{IN} = 0 or V+			0.01	1	μA

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SPECIFICATIONS (V+	= 5 V)						
		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C			
Parameter	Symbol	V+ = 5 V, \pm 10 %, V _{IN} = 0.6 V or 1.8 V ^e	Temp. ^a	Min. ^b	Typ. ^c	Max. ^b	Unit
Analog Switch							
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0		V+	v
On-Resistance	R _{ON}		Room Full		1	1.3 1.45	
R _{ON} Match	ΔR_{ON}	V+ = 4.5 V, V _{COM} = 0.5 V/2.5 V, I _{NO} , I _{NC} = 100 mA	Room			0.15	Ω
R _{ON} Flatness	R _{ON} Flatness	$n_{\rm NO}$, $n_{\rm NC} = 100$ mA	Room		0.3	0.4	
Switch Off Leakage Current	I _{NO(off)} I _{NC(off)}	V+ = 5.5 V,	Room Full	- 2 - 20		2 20	
Switch On Leakage Guilent	I _{COM(off)}	V_{NO}, V_{NC} = 1 V/4.5 V, V_{COM} = 4.5 V/1 V	Room Full	- 2 - 20		2 20	nA
Channel-On Leakage Current	I _{COM(on)}	V+ = 5.5 V, V _{NO} , V _{NC} = V _{COM} = 1 V/4.5 V	Room Full	- 2 - 20		2 20	
Digital Control							
Input High Voltage	V _{INH}		Full	1.8			v
Input Low Voltage	V _{INL}		Full			0.6	v
Input Capacitance	C _{in}		Full		4		pF
Input Current	$I_{\rm INL}$ or $I_{\rm INH}$	V _{IN} = 0 or V+	Full	1		1	μΑ
Dynamic Characteristics							
Turn-On Time	t _{ON}		Room Full		11	35 39	
Turn-Off Time	t _{OFF}	V_{NO} or V_{NC} = 2.5 V, R_L = 50 Ω , C_L = 35 pF	Room Full		6	31 33	ns
Break-Before-Make Time	t _{BBM}		Room	1	5		
Charge Injection ^d	Q _{INJ}	C_L = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω	Room		14		рС
Off-Isolation ^d	OIRR	R ₁ = 50 Ω, C ₁ = 5 pF, f = 1 MHz	Room		- 58		dB
Crosstalk ^d	X _{TALK}	112 - 3032, $02 - 301$, $1 - 10012$	Room		- 64		иБ
N _O , N _C Off Capacitance ^d	C _{NO(off)} C _{NC(off)}	V _{IN} = 0 or V+, f = 1 MHz	Room		19		pF
Channel-On Capacitance ^d	C _{ON}		Room		61		
Power Supply							
Power Supply Range	V+	V _{IN} = 0 or V+		1.8		5.5	V
Power Supply Current	l+	v _{IN} = 0 01 v+			0.01	1	μA

Notes:

a. Room = 25 °C, Full = as determined by the operating suffix.

b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.

c. Typical values are for design aid only, not guaranteed nor subject to production testing.

d. Guarantee by design, nor subjected to production test.

e. V_{IN} = input voltage to perform proper function.

f. Guaranteed by 5 V leakage testing, not production tested.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



100

10M

100

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



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DG2511, DG2512, DG2513

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V+ = 5.0 V

4.0

5.0

5

6



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

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DG2511, DG2512, DG2513

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TEST CIRCUITS



$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$



Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.













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TEST CIRCUITS



Figure 4. Off-Isolation



Figure 5. Channel Off/On Capacitance

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MINI QFN-6L CASE OUTLINE









DIM	М	ILLIMETER	S	INCHES			
DIW	MIN.	NAM.	MAX.	MIN.	NAM.	MAX.	
А	0.50	0.55	0.60	0.0197	0.0217	0.0236	
A1	0.00	-	0.05	0.000	-	0.002	
b	0.15	0.20	0.25	0.006	0.008	0.010	
с	0.15 REF			0.006 REF			
D	1.15	1.20	1.25	0.045	0.047	0.049	
E	0.95	1.00	1.05	0.037	0.039	0.041	
е	0.40 BSC				0.016 BSC		
L	0.30	0.35	0.40	0.012	0.014	0.016	
L1	0.40	0.45	0.50	0.016	0.018	0.020	

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DWG: 5958	



RECOMMENDED MINIMUM PADS FOR MINI QFN 6L



Mounting Footprint Dimensions in mm



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